

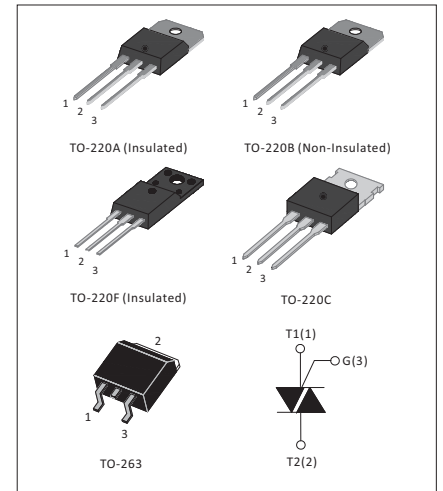
FEATURES

Available either in through hole or surface mount packages, the 12A series Triac is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits...or for phase control operation in light dimmers, motor speed controllers...

The snubberless versions are specially recommended for use on inductive loads, thanks to their high commutation performances.

MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	12	A
V_{RRM}	600/800/1200	V
V_{DRM}	600/800/1200	V



ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit	
Storage junction temperature range	T_{stg}	-40~150	°C	
Operating junction temperature range	T_j	-40~125	°C	
Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$)	V_{DRM}	600/800/1200	V	
Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$)	V_{RRM}	600/800/1200	V	
Non repetitive surge peak Off-state voltage	V_{DSM}	$V_{DRM}+100$	V	
Non repetitive peak reverse voltage	V_{RSM}	$V_{RRM}+100$	V	
RMS on-state current	$I_{T(RMS)}$	TO-220A(Ins)($T_c=90^\circ\text{C}$)	12	A
		TO-220B(Non-Ins)/TO-220C($T_c=105^\circ\text{C}$)		
		TO-220F(Ins)($T_c=79^\circ\text{C}$)		
		TO-263($T_c=115^\circ\text{C}$)		
Non repetitive surge peak on-state current(full cycle, F=50Hz)	I_{TSM}	120	A	
I^2t value for fusing ($t_p=10\text{ms}$)	I^2t	78	A^2s	
Critical rate of rise of on-state current($I_G=2 \times I_{GT}$)	I - II - III	d_i/d_t	50	A/us
Peak gate current	I_{GM}	4	A	
Average gate power dissipation	$P_{G(AV)}$	1	W	
Peak gate power	P_{GM}	5	W	

STATIC CHARACTERISTICS

Symbol	Parameter	Value(Max)	Unit
V_{TM}	$I_{TM}=17\text{A}, t_p=380\mu\text{s}$	1.5	V
I_{DRM}	$V_D=V_{DRM}, V_R=V_{RRM}, T_j=25^\circ\text{C}$	5	μA
I_{RRM}	$V_D=V_{DRM}, V_R=V_{RRM}, T_j=125^\circ\text{C}$	1	mA



ELECTRICAL CHARACTERISTICS($T_j=25^{\circ}\text{C}$ unless otherwise specified)

3 Quadrants								
Symbol	Test Condition	Quadrant		Value				Unit
				BW	CW	SW	TW	
I_{GT}	$V_D=12\text{V}, R_L=33\Omega$	I - II - III	Max	50	35	10	5	mA
V_{GT}		I - II - III	Max	1.3				
V_{GD}	$V_D=V_{DRM}, R_L=3.3\text{K}\Omega, T_j=125^{\circ}\text{C}$	I - II - III	Min	0.2				V
I_L	$I_G=1.2I_{GT}$	I - III	Max	80	50	30	20	mA
		II		90	60	40	30	
I_H	$I_T=100\text{mA}$		Max	60	40	20	15	mA
d_V/d_t	$V_0=2/3V_{DRM}, \text{Gate open}, T_j=125^{\circ}\text{C}$		Min	1000	500	200	100	V/uS

4 Quadrants								
Symbol	Test Condition	Quadrant		Value		Unit		
				B	C			
I_{GT}	$V_D=12\text{V}, R_L=33\Omega$	I - II - III	Max	50	25	mA		
		IV	Max	70	50			
V_{GT}	$V_D=12\text{V}, R_L=33\Omega$	All	Max	1.3		V		
V_{GD}	$V_D=V_{DRM}, R_L=3.3\text{K}\Omega, T_j=125^{\circ}\text{C}$	All	Min	0.2		V		
I_L	$I_G=1.2I_{GT}$	I - III - IV	Max	50	40	mA		
		II		100	80			
I_H	$I_T=100\text{mA}$		Max	50	25	mA		
d_V/d_t	$V_0=2/3V_{DRM}, \text{Gate open}, T_j=125^{\circ}\text{C}$		Min	500	200	V/uS		

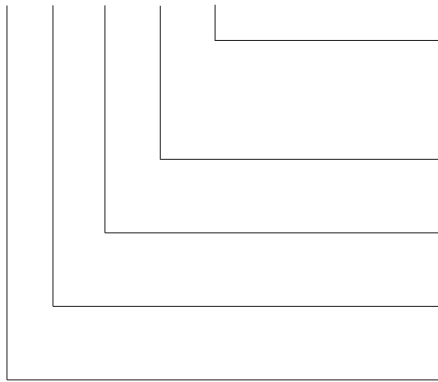
THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	TO-220A(Ins)	2.3	$^{\circ}\text{C}/\text{W}$
	TO-220B(Non-Ins)	1.4	
	TO-220C	1.4	
	TO-220F(Ins)	2.5	
	TO-263	1.4	



PRODUCT IDENTIFICATION

ST A 12A 60 BW



I_{GT}
 BW: $I_{GT1-3} \leq 50mA$ CW: $I_{GT1-3} \leq 35mA$ SW: $I_{GT1-3} \leq 10mA$ TW: $I_{GT1-3} \leq 5mA$
 B: $I_{GT1-3} \leq 50mA, I_{GT4} \leq 70mA$, C: $I_{GT1-3} \leq 25mA, I_{GT4} \leq 50mA$

V_{DRM}/V_{RRM}
 60: 600V 80:800V 120:1200V

$I_{T(RMS)}$
 12A: 12A

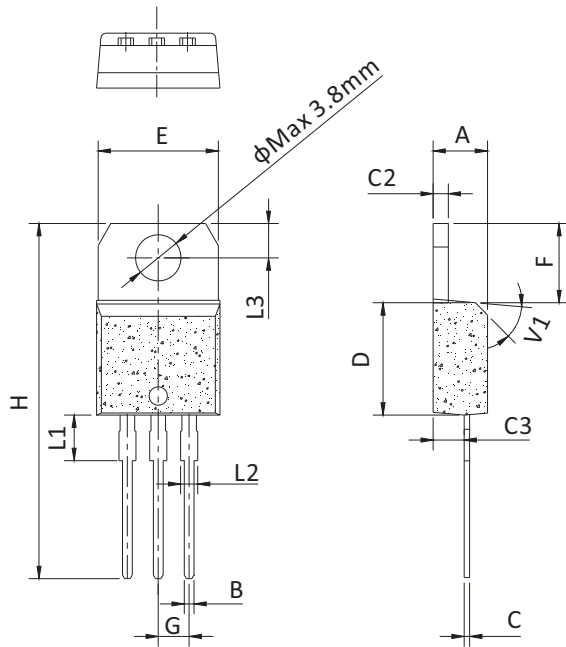
Package
 A: TO-220A B: TO-220B C: TO-220C F: TO-220F E: TO-263

Product Line
 ST: Semiware Triacs

PACKAGE MECHANICAL DATA

Ref.	Dimensions					
	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

TO-220A (Insulated)



PACKAGE MECHANICAL DATA

Ref.	Dimensions					
	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

Ref.	Dimensions					
	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
B	0.70		0.90	0.028		0.035
C	0.45		0.60	0.018		0.024
C2	1.23		1.32	0.048		0.052
C3	2.20		2.60	0.087		0.102
D	8.90		9.90	0.350		0.390
E	9.90		10.3	0.390		0.406
F	6.30		6.90	0.248		0.272
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.39			0.133	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
φ		3.6			0.142	



PACKAGE MECHANICAL DATA

Ref.	Dimensions					
	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	4.50		4.90	0.177		0.193
B	0.74		0.83	0.029		0.033
C	0.47		0.65	0.019		0.026
C2	2.45		2.75	0.096		0.108
C3	2.60		3.00	0.102		0.118
D	8.80		9.30	0.346		0.366
E	9.80		10.4	0.386		0.409
F	6.40		6.80	0.252		0.268
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.63			0.143	
L2	1.14		1.70	0.045		0.067
L3		3.30			0.130	
V1		45°			45°	

Ref.	Dimensions					
	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.40		9.60	0.370		0.378
D		2.54			0.100	
E	1.20		1.40	0.047		0.055
F	0.75		0.85	0.029		0.033
G			1.75			0.069
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0		0.25	0		0.010
M	1.25		1.35	0.049		0.053



FIG.1 Maximum Power Dissipation Versus RMS On-state Current

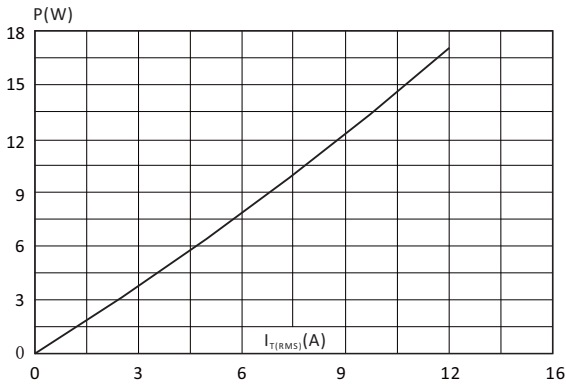


FIG.2 RMS On-state Current Versus Case Temperature

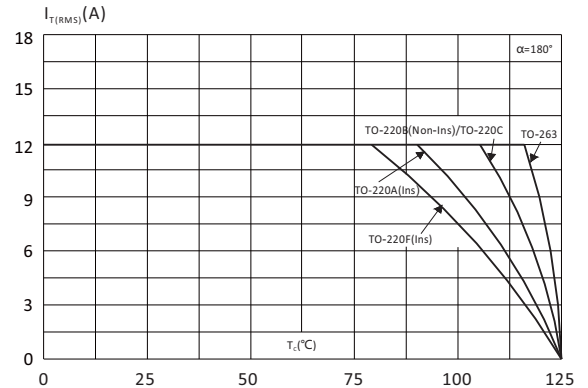


FIG.3 Surge Peak On-state Current Versus Number Of Cycles

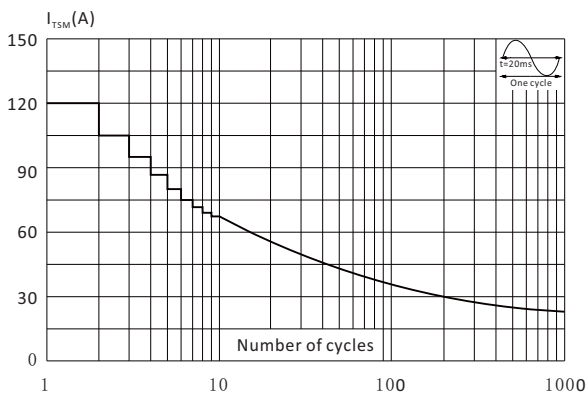


FIG.4 On-state Characteristics (Maximum Values)

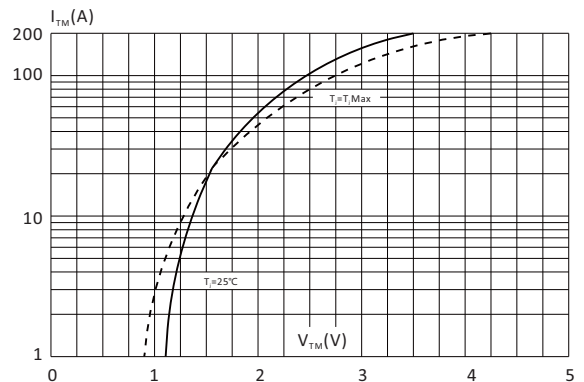


FIG.5 Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20ms$, and corresponding value of $I_t t$ ($dI/dt < 50A/\mu s$)

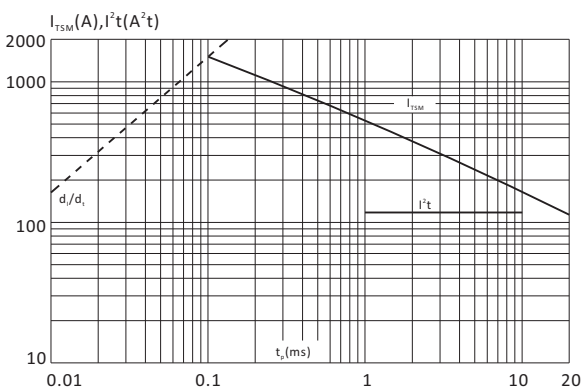
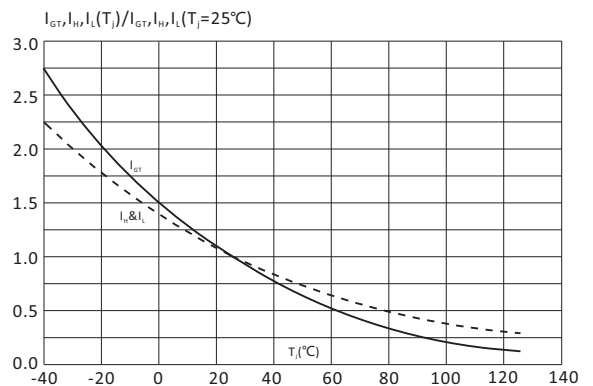


FIG.6 Relative variations of gate trigger current, holding current and latching current versus junction temperature



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